



Sample &

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SN74LVC1G02

SCES213X - APRIL 1999-REVISED APRIL 2014

SN74LVC1G02 Single 2-Input Positive NOR-Gate

Features 1

- Available in the Ultra-Small 0.64 mm² Package (DPW) with 0.5-mm Pitch
- Supports 5-V V_{CC} Operation
- Inputs Accept Voltages to 5.5 V
- Provides Down Translation to V_{CC}
- Max t_{pd} of 3.6 ns at 3.3 V
- Low Power Consumption, 10-µA Max I_{CC}
- ±24-mA Output Drive at 3.3 V
- Ioff Supports Live Insertion, Partial-Power-Down Mode, and Back-Drive Protection
- Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II
- ESD Protection Exceeds JESD 22
 - 2000-V Human-Body Model (A114-A)
 - 200-V Machine Model (A115-A)
 - 1000-V Charged-Device Model (C101)

Applications 2

- **AV Receiver**
- Audio Dock: Portable
- Blu-ray Player and Home Theater
- Embedded PC
- MP3 Player/Recorder (Portable Audio)
- Personal Digital Assistant (PDA)
- Power: Telecom/Server AC/DC Supply: Single Controller: Analog and Digital
- Solid State Drive (SSD): Client and Enterprise
- TV: LCD/Digital and High-Definition (HDTV)
- Tablet: Enterprise
- Video Analytics: Server
- Wireless Headset, Keyboard, and Mouse

4 **Simplified Schematic**



3 Description

This single 2-input positive-NOR gate is designed for 1.65-V to 5.5-V V_{CC} operation.

The SN74LVC1G02 performs the Boolean function $Y = \overline{A + B}$ or $Y = \overline{A} \cdot \overline{B}$ in positive logic.

The CMOS device has high output drive while maintaining low static power dissipation over a broad V_{CC} operating range.

The SN74LVC1G02 device is available in a variety of packages, including the ultra-small DPW package with a body size of 0.8×0.8 mm.

Device Information⁽¹⁾

DEVICE NAME	PACKAGE	BODY SIZE
	SOT-23 (5)	2.9mm × 1.6mm
	SC70 (5)	2.0mm × 1.25mm
SN74LVC1G02	SON (6)	1.45mm × 1.0mm
	DSBGA (5)	1.41mm × 0.91mm
	X2SON (4)	0.8mm × 0.8mm

(1) For all available packages, see the orderable addendum at the end of the datasheet.



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5 Revision History

C	hanges from Revision W (February 2014) to Revision X	Page
•	Updated Features, Description, and Device Information table	
•	Added Pin Functions table.	3
•	Added Thermal Information table.	5
•	Added Detailed Description section.	10
•	Added Application and Implementation section.	11
•	Added Layout section.	12

Changes from Revision V (December 2013) to Revision W

Changes from Revision T (November 2012) to Revision U

Ch	hanges from Revision U (November 2013) to Revision V Pag
•	Moved T _{stg} to Handling Ratings table
•	Added Device Information table.
	Added DPW Package.

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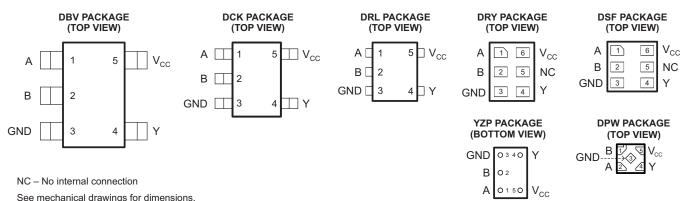
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6 Pin Configuration and Functions



See mechanical drawings for dimensions.

Pin Functions

	PI	N		
NAME	DBV, DCK, DRL, YZP	DRY, DSF	DPW	DESCRIPTION
A	1	1	2	Input
В	B 2 2		1	Input
GND	3	3	3	Ground
Y	4	4	4	Output
V _{CC}	V _{CC} 5 6 5 NC - 5 -		Power terminal	
NC			-	Not connected

7 Specifications

7.1 Absolute Maximum Ratings⁽¹⁾

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT
V _{CC}	Supply voltage range		-0.5	6.5	V
VI	Input voltage range		-0.5	6.5	V
Vo	Voltage range applied to any output in the	tage range applied to any output in the high-impedance or power-off state ⁽²⁾			
Vo	Voltage range applied to any output in the	-0.5	V _{CC} + 0.5	V	
I _{IK}	Input clamp current	V ₁ < 0		-50	mA
I _{OK}	Output clamp current	V _O < 0		-50	mA
I _O	Continuous output current		±50	mA	
	Continuous current through V_{CC} or GND			±100	mA

(1) Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

(2) The input and output negative-voltage ratings may be exceeded if the input and output current ratings are observed.

(3) The value of V_{CC} is provided in the *Recommended Operating Conditions* table.

7.2 Handling Ratings

	PARAMETER	DEFINITION	MIN	MAX	UNIT
T _{stg}		Storage temperature range	-65	150	°C
		Human body model (HBM), per ANSI/ESDA/JEDEC JS-001, all pins ⁽¹⁾	0	2	
$V_{(ESD)}$	Electrostatic	Charged device model (CDM), per JEDEC specification JESD22-C101, all pins ⁽²⁾	0	1	kV

(1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

(2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.



7.3 Recommended Operating Conditions⁽¹⁾

			MIN	MAX	UNIT
V	High-level input voltage Low-level input voltage Input voltage Output voltage High-level output current Low-level output current	Operating	1.65	5.5	V
V _{CC}		Data retention only	1.5		V
		V _{CC} = 1.65 V to 1.95 V	$0.65 \times V_{CC}$		
V		V_{CC} = 2.3 V to 2.7 V	1.7		V
VIH	High-level liput voltage	V_{CC} = 3 V to 3.6 V	2		V
		V_{CC} = 4.5 V to 5.5 V	$0.7 \times V_{CC}$		
		V_{CC} = 1.65 V to 1.95 V		$0.35 \times V_{CC}$	
V		V_{CC} = 2.3 V to 2.7 V		0.7	V
VIL	Low-level input voltage	V_{CC} = 3 V to 3.6 V		0.8	V
	High-level input voltage Low-level input voltage Input voltage Output voltage High-level output current Low-level output current v Input transition rise or fall rate	V_{CC} = 4.5 V to 5.5 V		$0.3 \times V_{CC}$	
VI	Input voltage	·	0	5.5	V
Vo	Output voltage		0	V_{CC}	V
		V _{CC} = 1.65 V		-4	
		$V_{CC} = 2.3 V$		-8	
I _{OH}	High-level output current	$V_{CC} = 3 V$		-16	mA
	H High-level input voltage L Low-level input voltage Input voltage Output voltage O Output voltage H High-level output current L Low-level output current L Low-level output current	VCC = 3 V		-24	
	High-level input voltage Low-level input voltage Input voltage Output voltage H High-level output current Low-level output current ΛΔν Input transition rise or fall rate	$V_{CC} = 4.5 V$		-32	
		V _{CC} = 1.65 V		4	
	$_{H}$ High-level input voltage $_{H}$ Low-level input voltage $_{h}$ Input voltage $_{O}$ Output voltage $_{H}$ High-level output current $_{H}$ Low-level output current $_{L}$ Low-level output current $_{L}$ Input transition rise or fall rate	$V_{CC} = 2.3 V$		8	
I _{OL}	Low-level output current	$V_{CC} = 3 V$		16	mA
	Low-level input voltage Input voltage Output voltage High-level output current Low-level output current Δν Input transition rise or fall rate	V _{CC} = 3 V		24	
		$V_{CC} = 4.5 V$		32	
		V_{CC} = 1.8 V ± 0.15 V, 2.5 V ± 0.2 V		20	
Δt/Δv	Input transition rise or fall rate	$V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$		10	ns/V
		$V_{CC} = 5 V \pm 0.5 V$		5	
T _A	Operating free-air temperature		-40	125	°C

(1) All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.

7.4 Thermal Information

		SN74LVC1G02								
	THERMAL METRIC ⁽¹⁾	DBV	DCK	DRL	DRY	YZP	DPW	UNIT		
		5 PINS	5 PINS	5 PINS	6 PINS	5 PINS	4 PINS			
R_{\thetaJA}	Junction-to-ambient thermal resistance	229	278	243	439	130	340			
R _{0JCtop}	Junction-to-case (top) thermal resistance	164	93	78	277	54	215			
$R_{\theta JB}$	Junction-to-board thermal resistance	62	65	78	271	51	294	80 AM		
ψ_{JT}	Junction-to-top characterization parameter	44	2	10	84	1	41	°C/W		
ψ_{JB}	Junction-to-board characterization parameter	62	64	77	271	50	294			
$R_{\theta JCbot}$	Junction-to-case (bottom) thermal resistance	-	-	-	-	-	250			

(1) For more information about traditional and new thermal metrics, see the IC Package Thermal Metrics application report, SPRA953.

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7.5 Electrical Characteristics

over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER				–40°C	to 85°C		–40°C			
V _{OH} V _{OL} I _I I _{off}	AMETER	TEST CONDITIONS	V _{cc}	MIN	TYP ⁽¹⁾	IAX	MIN	TYP ⁽¹⁾	MAX	UNIT
		I _{OH} = -100 μA	1.65 V to 5.5 V	V _{CC} - 0.1			V _{CC} - 0.1			
		$I_{OH} = -4 \text{ mA}$	1.65 V	1.2			1.2			
Vau		$I_{OH} = -8 \text{ mA}$	2.3 V	1.9			1.9			V
PARAMETER V _{OH} V _{OL} I _I A or B inputs I _{off} I _{CC}	I _{OH} = -16 mA	2.1/	2.4			2.4			v	
		I _{OH} = -24 mA	3 V	2.3			2.3			
		I _{OH} = -32 mA	4.5 V	3.8			3.8			
		I _{OL} = 100 μA	1.65 V to 5.5 V			0.1			0.1	
		I _{OL} = 4 mA	1.65 V		().45			0.45	
V		I _{OL} = 8 mA	2.3 V			0.3			0.3	V
VOL		I _{OL} = 16 mA	3 V			0.4			0.4	v
		I _{OL} = 24 mA	3 V		().55			0.55	
		I _{OL} = 32 mA	4.5 V		().55			0.55	
I _I		V _I = 5.5 V or GND	0 to 5.5 V			±5			±5	μA
I _{off}		$V_{\rm I}$ or $V_{\rm O}$ = 5.5 V	0			±10			±10	μA
I _{CC}		$V_{I} = 5.5 \text{ V or GND}$ $I_{O} = 0$	1.65 V to 5.5 V			10			10	μA
ΔI _{CC}		One input at $V_{CC} - 0.6 V$, Other inputs at V_{CC} or GND	3 V to 5.5 V			500			500	μA
Ci		$V_{I} = V_{CC}$ or GND	3.3 V		4			4		pF

(1) All typical values are at V_{CC} = 3.3 V, T_A = 25°C.

7.6 Switching Characteristics, $C_L = 15 \text{ pF}$

over recommended operating free-air temperature range, $C_L = 15 \text{ pF}$ (unless otherwise noted) (see Figure 3)

						–40°C	to 85°C				
PARAMETER	FROM (INPUT)	TO (OUTPUT)	V _{CC} = 1.8 V ± 0.15 V		V _{CC} = 2.5 V ± 0.2 V		V _{CC} = 3.3 V ± 0.3 V		V _{CC} = 5 V ± 0.5 V		UNIT
			MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
t _{pd}	A or B	Y	1.9	7.2	0.8	4.4	0.8	3.6	0.8	3.4	ns

7.7 Switching Characteristics, -40°C to 85°C

over recommended operating free-air temperature range, C_L = 30 pF or 50 pF (unless otherwise noted) (see Figure 4)

			–40°C to 85°C								
PARAMETER	FROM (INPUT)	TO (OUTPUT)	V _{CC} = 1.8 V ± 0.15 V		V _{CC} = 2.5 V ± 0.2 V		V _{CC} = 3.3 V ± 0.3 V		V _{CC} = 5 V ± 0.5 V		UNIT
			MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
t _{pd}	A or B	Y	2.8	8	1.2	5.5	1	4.5	1	4	ns

7.8 Switching Characteristics, -40°C to 125°C

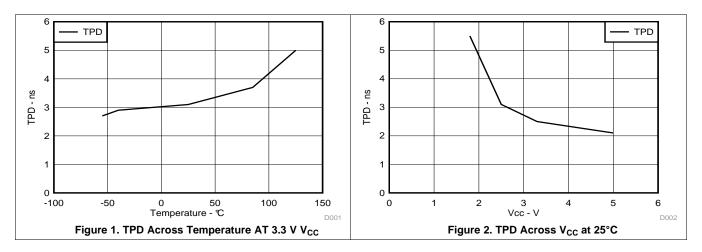
						–40°C t	o 125°C				
PARAMETER	FROM (INPUT)			V _{CC} = 1.8 V ± 0.15 V		V _{CC} = 2.5 V ± 0.2 V		3.3 V .3 V	V _{CC} = 5 V ± 0.5 V		UNIT
			MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
t _{pd}	A or B	Y	2.8	9	1.2	6	1.0	5	1	4.5	ns



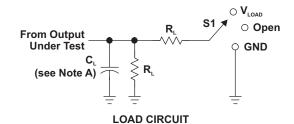
7.9 Operating Characteristics

$T_A = 2$	25°C						
	PARAMETER	TEST	V _{CC} = 1.8 V	V _{CC} = 2.5 V	V _{CC} = 3.3 V	$V_{CC} = 5 V$	UNIT
	FARAMETER	CONDITIONS	ТҮР	TYP	TYP	ТҮР	UNIT
C _{pd}	Power dissipation capacitance	f = 10 MHz	23	23	23	25	pF

7.10 Typical Characteristics

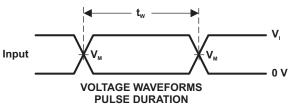


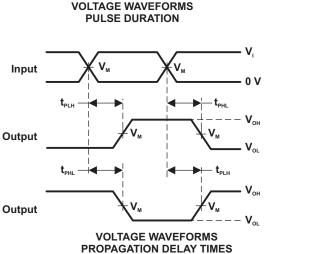
8 Parameter Measurement Information



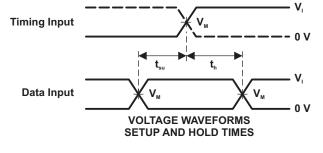
TEST	S1
t_{PLH}/t_{PHL}	Open
t_{PLZ}/t_{PZL}	VLOAD
t_{PHZ}/t_{PZH}	GND

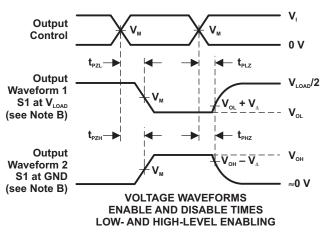
	INF	PUTS				1	
V _{cc}	V	t,/t,	V _M	VLOAD	CL	R	V
1.8 V ± 0.15 V	V _{cc}	≤2 ns	V _{cc} /2	2 × V _{cc}	15 pF	1 Μ Ω	0.15 V
$2.5 V \pm 0.2 V$	V_{cc}	≤2 ns	V _{cc} /2	$2 \times V_{cc}$	15 pF	1 Μ Ω	0.15 V
$3.3 V \pm 0.3 V$	3 V	≤2.5 ns	1.5 V	6 V	15 pF	1 Μ Ω	0.3 V
$5 V \pm 0.5 V$	V_{cc}	≤2.5 ns	V _{cc} /2	2 × V _{cc}	15 pF	1 Μ Ω	0.3 V





INVERTING AND NONINVERTING OUTPUTS





NOTES: A. C_L includes probe and jig capacitance.

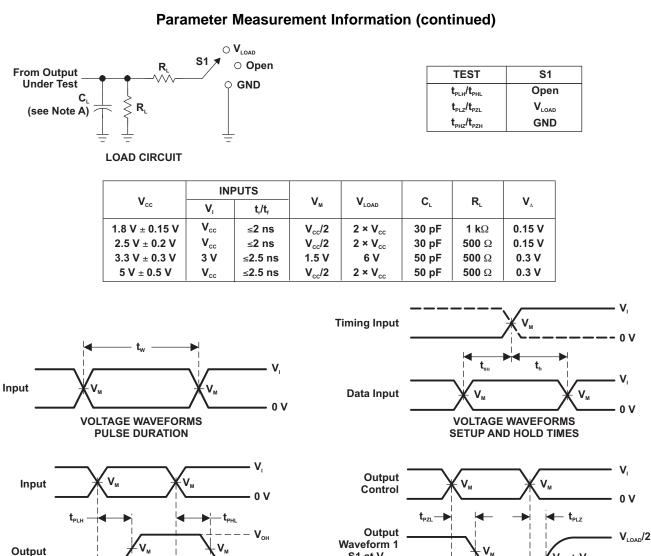
- B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
 C. All input pulses are supplied by generators having the following characteristics: PRR ≤ 10 MHz, Z₀ = 50 Ω.
- D. The outputs are measured one at a time, with one transition per measurement.
- E. t_{PLZ} and t_{PHZ} are the same as t_{dis} .
- F. t_{PZL} and t_{PHZ} are the same as t_{en} .
- G. t_{PLH} and t_{PHL} are the same as t_{pd} .
- H. All parameters and waveforms are not applicable to all devices.

Figure 3. Load Circuits and Voltage Waveforms



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NOTES: A. C_{L} includes probe and jig capacitance.

VOLTAGE WAVEFORMS

PROPAGATION DELAY TIMES

INVERTING AND NONINVERTING OUTPUTS

t_{PHL}

Output

B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control. C. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, Z_o = 50 Ω .

S1 at VLOAD (see Note B)

Output

Waveform 2

(see Note B)

S1 at GND

t_{PZH}

V.

VOLTAGE WAVEFORMS

ENABLE AND DISABLE TIMES

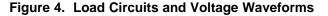
LOW- AND HIGH-LEVEL ENABLING

D. The outputs are measured one at a time, with one transition per measurement.

Vol

t_{PLP}

- E. t_{PLZ} and \dot{t}_{PHZ} are the same as t_{dis} .
- F. $t_{_{PZL}}$ and $t_{_{PZH}}$ are the same as $t_{_{en}}$.
- G. $t_{\mbox{\tiny PLH}}$ and $t_{\mbox{\tiny PHL}}$ are the same as $t_{\mbox{\tiny pd}}$
- H. All parameters and waveforms are not applicable to all devices.



t_{PH7}

 V_{OH}

≈0 V

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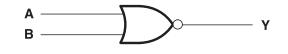
9 Detailed Description

9.1 Overview

The SN74LVC1G02 device contains one 2-input positive-NOR gate and performs the Boolean function $Y = \overline{A} + \overline{B}$ or $Y = \overline{A} \cdot \overline{B}$. This device is fully specified for partial-power-down applications using I_{off} . The I_{off} circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down.

The DPW package technology is a major breakthrough in IC packaging. Its tiny 0.64 mm square footprint saves significant board space over other package options while still retaining the traditional manufacturing friendly lead pitch of 0.5 mm.

9.2 Functional Block Diagram



9.3 Feature Description

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- Wide operating voltage range.
 - Operates from 1.65 V to 5.5 V.
 - Allows down voltage translation.
- Inputs accept voltages to 5.5 V.
- I_{off} feature allows voltages on the inputs and outputs, when V_{CC} is 0 V.

9.4 Device Functional Modes

Function Table

INP	UTS	OUTPUT
А	В	Y
Н	Х	L
Х	Н	L
L	L	Н

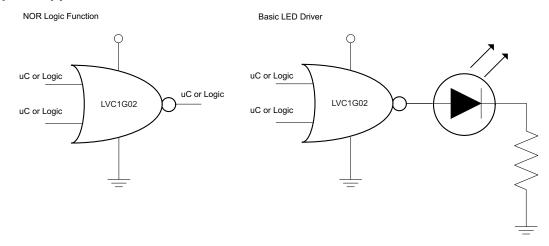


10 Application and Implementation

10.1 Application Information

The SN74LVC1G02 is a high drive CMOS device that can be used for implement NOR logic with a high output drive, such as an LED application. It can produce 24-mA of drive current at 3.3 V making it Ideal for driving multiple outputs and good for high speed applications up to 100 Mhz. The inputs are 5.5-V tolerant allowing translation down to V_{CC} .

10.2 Typical Application



10.2.1 Design Requirements

This device uses CMOS technology and has balanced output drive. Care should be taken to avoid bus contention because it can drive currents that would exceed maximum limits. The high drive will also create fast edges into light loads, so routing and load conditions should be considered to prevent ringing.

10.2.2 Detailed Design Procedure

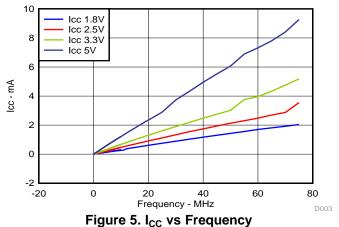
- 1. Recommended Input Conditions:
 - Rise time and fall time specs. See ($\Delta t/\Delta V$) in the Recommended Operating Conditions table.
 - Specified high and low levels. See (V_{IH} and V_{IL}) in the Recommended Operating Conditions table.
 - Inputs are overvoltage tolerant allowing them to go as high as (V₁ max) in the Recommended Operating Conditions table at any valid V_{CC}.
- 2. Recommend Output Conditions:
 - Load currents should not exceed (I_O max) per output and should not exceed total current (continuous current through V_{CC} or GND) for the part. These limits are located in the Absolute Maximum Ratings table.
 - Outputs should not be pulled above V_{CC}.

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Typical Application (continued)

10.2.3 Application Curves



11 Power Supply Recommendations

The power supply can be any voltage between the min and max supply voltage rating located in the Recommended Operating Conditions table.

Each VCC pin should have a good bypass capacitor to prevent power disturbance. For devices with a single supply, a 0.1- μ F capacitor is recommended. If there are multiple VCC pins, then a 0.01- μ F or 0.022- μ F capacitor is recommended for each power pin. It is ok to parallel multiple bypass capacitors to reject different frequencies of noise. A 0.1- μ F and 1- μ F capacitors are commonly used in parallel. The bypass capacitor should be installed as close to the power pin as possible for best results.

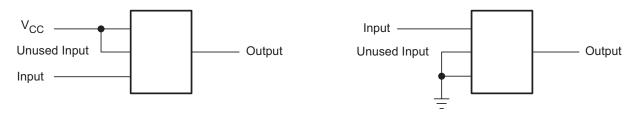
12 Layout

12.1 Layout Guidelines

When using multiple bit logic devices inputs should not ever float.

In many cases, functions or parts of functions of digital logic devices are unused; for example, when only two inputs of a triple-input AND gate are used or only 3 of the 4 buffer gates are used. Such input pins should not be left unconnected because the undefined voltages at the outside connections result in undefined operational states. Specified below are the rules that must be observed under all circumstances. All unused inputs of digital logic devices must be connected to a high or low bias to prevent them from floating. The logic level that should be applied to any particular unused input depends on the function of the device. Generally they will be tied to GND or VCC, whichever makes more sense or is more convenient.

12.2 Layout Example





13 Device and Documentation Support

13.1 Trademarks

All trademarks are the property of their respective owners.

13.2 Electrostatic Discharge Caution



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

13.3 Glossary

SLYZ022 — TI Glossary.

This glossary lists and explains terms, acronyms and definitions.

14 Mechanical, Packaging, and Orderable Information

The following pages include mechanical packaging and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.



PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
SN74LVC1G02DBVR	ACTIVE	SOT-23	DBV	5	3000	RoHS & Green	NIPDAU SN	Level-1-260C-UNLIM	-40 to 125	(C025, C02F, C02J, C02R) (C02H, C02P, C02S)	Samples
SN74LVC1G02DBVRE4	ACTIVE	SOT-23	DBV	5	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	C02F	Samples
SN74LVC1G02DBVRG4	ACTIVE	SOT-23	DBV	5	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	C02F	Samples
SN74LVC1G02DBVT	ACTIVE	SOT-23	DBV	5	250	RoHS & Green	NIPDAU SN	Level-1-260C-UNLIM	-40 to 125	(C025, C02F, C02J, C02R) (C02H, C02P, C02S)	Samples
SN74LVC1G02DBVTG4	ACTIVE	SOT-23	DBV	5	250	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	C02F	Samples
SN74LVC1G02DCKR	ACTIVE	SC70	DCK	5	3000	RoHS & Green	NIPDAU SN	Level-1-260C-UNLIM	-40 to 125	(CB5, CBF, CBJ, CB K, CBR) (CBH, CBP, CBS)	Samples
SN74LVC1G02DCKRE4	ACTIVE	SC70	DCK	5	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	CB5 CBS	Samples
SN74LVC1G02DCKRG4	ACTIVE	SC70	DCK	5	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	CB5 CBS	Samples
SN74LVC1G02DCKT	ACTIVE	SC70	DCK	5	250	RoHS & Green	NIPDAU SN	Level-1-260C-UNLIM	-40 to 125	(CB5, CBF, CBJ, CB K, CBR) (CBH, CBP, CBS)	Samples
SN74LVC1G02DCKTG4	ACTIVE	SC70	DCK	5	250	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	CB5 CBS	Samples
SN74LVC1G02DPWR	ACTIVE	X2SON	DPW	5	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	J4	Samples
SN74LVC1G02DRLR	ACTIVE	SOT-5X3	DRL	5	4000	RoHS & Green	NIPDAUAG	Level-1-260C-UNLIM	-40 to 125	(CB7, CBR)	Samples
SN74LVC1G02DRY2	ACTIVE	SON	DRY	6	5000	RoHS & Green	NIPDAU NIPDAUAG	Level-1-260C-UNLIM	-40 to 125	СВ	Samples
SN74LVC1G02DRYR	ACTIVE	SON	DRY	6	5000	RoHS & Green	NIPDAU NIPDAUAG	Level-1-260C-UNLIM	-40 to 125	СВ	Samples
SN74LVC1G02DSF2	ACTIVE	SON	DSF	6	5000	RoHS & Green	NIPDAU NIPDAUAG	Level-1-260C-UNLIM	-40 to 125	СВ	Samples



Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
SN74LVC1G02DSFR	ACTIVE	SON	DSF	6	5000	RoHS & Green	NIPDAU NIPDAUAG	Level-1-260C-UNLIM	-40 to 125	СВ	Samples
SN74LVC1G02YZPR	ACTIVE	DSBGA	YZP	5	3000	RoHS & Green	SNAGCU	Level-1-260C-UNLIM	-40 to 85	(CB7, CBN)	Samples

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

⁽²⁾ RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

⁽³⁾ MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

⁽⁴⁾ There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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OTHER QUALIFIED VERSIONS OF SN74LVC1G02 :



• Enhanced Product : SN74LVC1G02-EP

NOTE: Qualified Version Definitions:

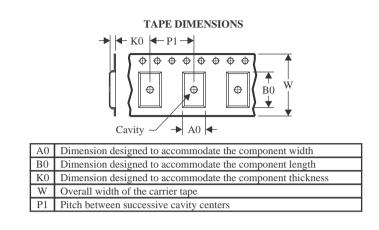
• Enhanced Product - Supports Defense, Aerospace and Medical Applications

Texas

STRUMENTS

TAPE AND REEL INFORMATION





QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



Device	-	Package	Pins	SPQ	Reel	Reel	A0	B 0	К0	P1	W,	Pin1
	Туре	Drawing			Diameter (mm)	Width W1 (mm)	(mm)	(mm)	(mm)	(mm)	(mm)	Quadrant
SN74LVC1G02DBVR	SOT-23	DBV	5	3000	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
SN74LVC1G02DBVR	SOT-23	DBV	5	3000	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
SN74LVC1G02DBVRG4	SOT-23	DBV	5	3000	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3
SN74LVC1G02DBVT	SOT-23	DBV	5	250	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
SN74LVC1G02DBVT	SOT-23	DBV	5	250	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
SN74LVC1G02DBVTG4	SOT-23	DBV	5	250	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3
SN74LVC1G02DCKR	SC70	DCK	5	3000	180.0	8.4	2.3	2.5	1.2	4.0	8.0	Q3
SN74LVC1G02DCKRG4	SC70	DCK	5	3000	178.0	9.2	2.4	2.4	1.22	4.0	8.0	Q3
SN74LVC1G02DCKT	SC70	DCK	5	250	180.0	8.4	2.3	2.5	1.2	4.0	8.0	Q3
SN74LVC1G02DCKTG4	SC70	DCK	5	250	178.0	9.2	2.4	2.4	1.22	4.0	8.0	Q3
SN74LVC1G02DPWR	X2SON	DPW	5	3000	178.0	8.4	0.91	0.91	0.5	2.0	8.0	Q3
SN74LVC1G02DRLR	SOT-5X3	DRL	5	4000	180.0	8.4	1.98	1.78	0.69	4.0	8.0	Q3
SN74LVC1G02DRY2	SON	DRY	6	5000	180.0	8.4	1.65	1.2	0.7	4.0	8.0	Q3
SN74LVC1G02DRY2	SON	DRY	6	5000	180.0	9.5	1.6	1.15	0.75	4.0	8.0	Q3
SN74LVC1G02DRYR	SON	DRY	6	5000	180.0	9.5	1.15	1.6	0.75	4.0	8.0	Q1
SN74LVC1G02DSF2	SON	DSF	6	5000	180.0	9.5	1.16	1.16	0.5	4.0	8.0	Q3



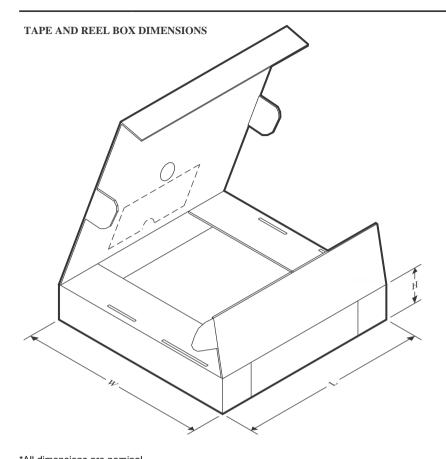
25-Sep-2024

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74LVC1G02DSF2	SON	DSF	6	5000	180.0	8.4	1.16	1.16	0.63	4.0	8.0	Q3
SN74LVC1G02DSFR	SON	DSF	6	5000	180.0	9.5	1.16	1.16	0.5	4.0	8.0	Q2
SN74LVC1G02YZPR	DSBGA	YZP	5	3000	178.0	9.2	1.02	1.52	0.63	4.0	8.0	Q1



PACKAGE MATERIALS INFORMATION

25-Sep-2024



Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74LVC1G02DBVR	SOT-23	DBV	5	3000	210.0	185.0	35.0
SN74LVC1G02DBVR	SOT-23	DBV	5	3000	210.0	185.0	35.0
SN74LVC1G02DBVRG4	SOT-23	DBV	5	3000	180.0	180.0	18.0
SN74LVC1G02DBVT	SOT-23	DBV	5	250	210.0	185.0	35.0
SN74LVC1G02DBVT	SOT-23	DBV	5	250	210.0	185.0	35.0
SN74LVC1G02DBVTG4	SOT-23	DBV	5	250	180.0	180.0	18.0
SN74LVC1G02DCKR	SC70	DCK	5	3000	210.0	185.0	35.0
SN74LVC1G02DCKRG4	SC70	DCK	5	3000	180.0	180.0	18.0
SN74LVC1G02DCKT	SC70	DCK	5	250	210.0	185.0	35.0
SN74LVC1G02DCKTG4	SC70	DCK	5	250	180.0	180.0	18.0
SN74LVC1G02DPWR	X2SON	DPW	5	3000	205.0	200.0	33.0
SN74LVC1G02DRLR	SOT-5X3	DRL	5	4000	202.0	201.0	28.0
SN74LVC1G02DRY2	SON	DRY	6	5000	202.0	201.0	28.0
SN74LVC1G02DRY2	SON	DRY	6	5000	184.0	184.0	19.0
SN74LVC1G02DRYR	SON	DRY	6	5000	184.0	184.0	19.0
SN74LVC1G02DSF2	SON	DSF	6	5000	184.0	184.0	19.0
SN74LVC1G02DSF2	SON	DSF	6	5000	202.0	201.0	28.0
SN74LVC1G02DSFR	SON	DSF	6	5000	184.0	184.0	19.0



25-Sep-2024

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74LVC1G02YZPR	DSBGA	YZP	5	3000	220.0	220.0	35.0

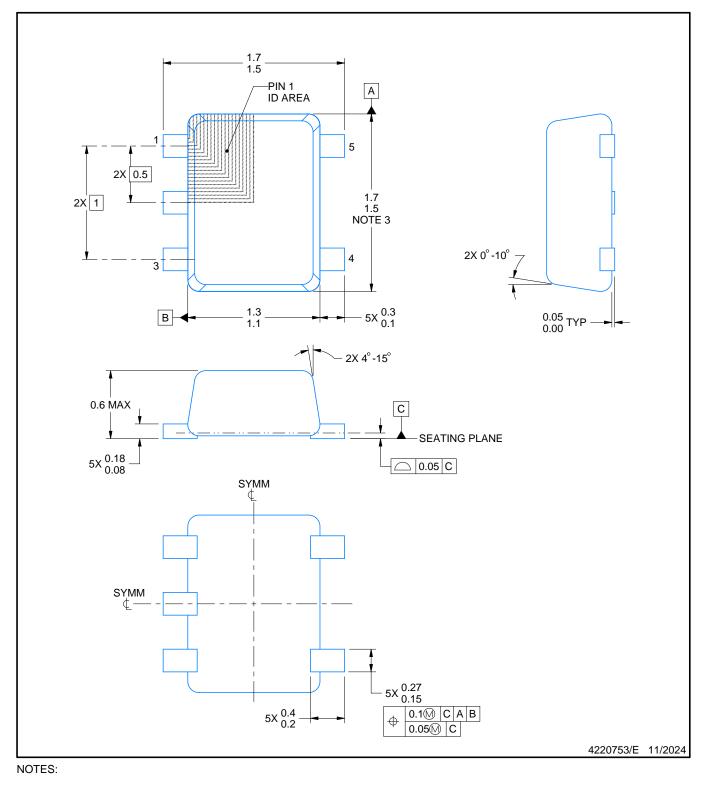
DRL0005A



PACKAGE OUTLINE

SOT - 0.6 mm max height

PLASTIC SMALL OUTLINE



- All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
 This drawing is subject to change without notice.
 This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side. 4. Reference JEDEC registration MO-293 Variation UAAD-1

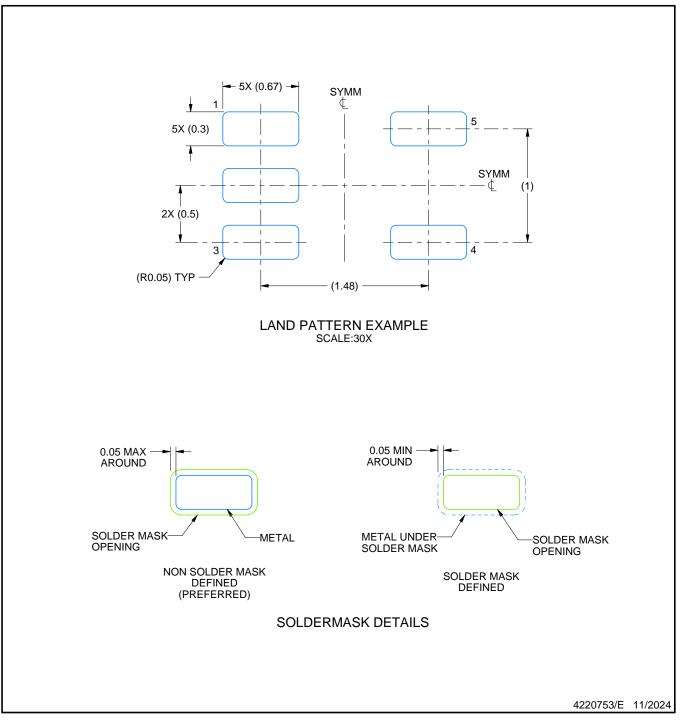


DRL0005A

EXAMPLE BOARD LAYOUT

SOT - 0.6 mm max height

PLASTIC SMALL OUTLINE



NOTES: (continued)

5. Publication IPC-7351 may have alternate designs.

6. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

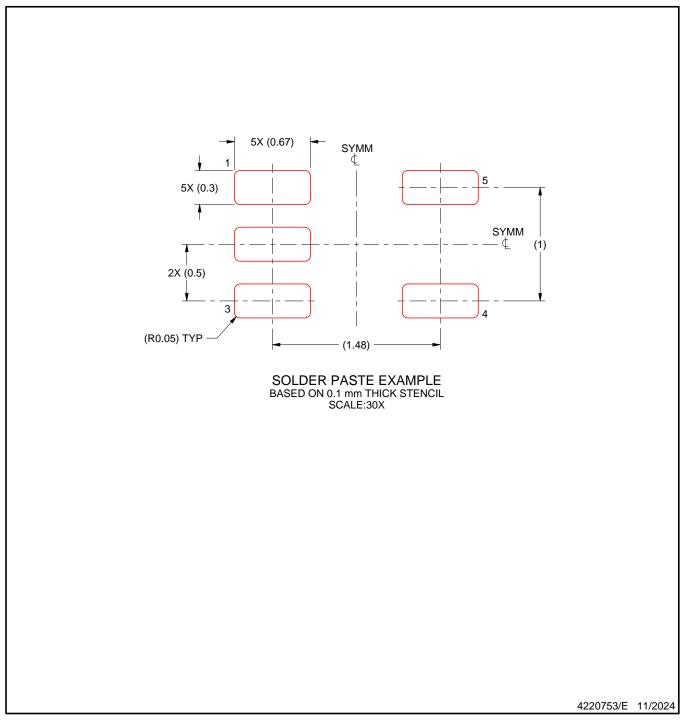


DRL0005A

EXAMPLE STENCIL DESIGN

SOT - 0.6 mm max height

PLASTIC SMALL OUTLINE



NOTES: (continued)

7. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

8. Board assembly site may have different recommendations for stencil design.



GENERIC PACKAGE VIEW

X2SON - 0.4 mm max height PLASTIC SMALL OUTLINE - NO LEAD



Images above are just a representation of the package family, actual package may vary. Refer to the product data sheet for package details.



4211218-3/D

DPW0005A



PACKAGE OUTLINE

X2SON - 0.4 mm max height

PLASTIC SMALL OUTLINE - NO LEAD



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.2. This drawing is subject to change without notice.
- 3. The size and shape of this feature may vary.



DPW0005A

EXAMPLE BOARD LAYOUT

X2SON - 0.4 mm max height

PLASTIC SMALL OUTLINE - NO LEAD



NOTES: (continued)

4. This package is designed to be soldered to a thermal pad on the board. For more information, refer to QFN/SON PCB application note in literature No. SLUA271 (www.ti.com/lit/slua271).



DPW0005A

EXAMPLE STENCIL DESIGN

X2SON - 0.4 mm max height

PLASTIC SMALL OUTLINE - NO LEAD



NOTES: (continued)

5. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.



YZP0005



PACKAGE OUTLINE

DSBGA - 0.5 mm max height

DIE SIZE BALL GRID ARRAY



- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
- 2. This drawing is subject to change without notice.



YZP0005

EXAMPLE BOARD LAYOUT

DSBGA - 0.5 mm max height

DIE SIZE BALL GRID ARRAY



NOTES: (continued)

3. Final dimensions may vary due to manufacturing tolerance considerations and also routing constraints. For more information, see Texas Instruments literature number SNVA009 (www.ti.com/lit/snva009).



YZP0005

EXAMPLE STENCIL DESIGN

DSBGA - 0.5 mm max height

DIE SIZE BALL GRID ARRAY



NOTES: (continued)

4. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release.



DCK0005A



PACKAGE OUTLINE

SOT - 1.1 max height

SMALL OUTLINE TRANSISTOR



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
 This drawing is subject to change without notice.
 Reference JEDEC MO-203.

- 4. Support pin may differ or may not be present.5. Lead width does not comply with JEDEC.
- 6. Body dimensions do not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.25mm per side



DCK0005A

EXAMPLE BOARD LAYOUT

SOT - 1.1 max height

SMALL OUTLINE TRANSISTOR



NOTES: (continued)

Publication IPC-7351 may have alternate designs.
 Solder mask tolerances between and around signal pads can vary based on board fabrication site.



DCK0005A

EXAMPLE STENCIL DESIGN

SOT - 1.1 max height

SMALL OUTLINE TRANSISTOR



NOTES: (continued)

9. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

10. Board assembly site may have different recommendations for stencil design.



DBV0005A



PACKAGE OUTLINE

SOT-23 - 1.45 mm max height

SMALL OUTLINE TRANSISTOR



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
 This drawing is subject to change without notice.
 Reference JEDEC MO-178.

- 4. Body dimensions do not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.25 mm per side.
- 5. Support pin may differ or may not be present.



DBV0005A

EXAMPLE BOARD LAYOUT

SOT-23 - 1.45 mm max height

SMALL OUTLINE TRANSISTOR



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



DBV0005A

EXAMPLE STENCIL DESIGN

SOT-23 - 1.45 mm max height

SMALL OUTLINE TRANSISTOR



NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

9. Board assembly site may have different recommendations for stencil design.



GENERIC PACKAGE VIEW

USON - 0.6 mm max height PLASTIC SMALL OUTLINE - NO LEAD



Images above are just a representation of the package family, actual package may vary. Refer to the product data sheet for package details.



4207181/G

DRY0006A



PACKAGE OUTLINE

USON - 0.6 mm max height

PLASTIC SMALL OUTLINE - NO LEAD



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M. 2. This drawing is subject to change without notice.



DRY0006A

EXAMPLE BOARD LAYOUT

USON - 0.6 mm max height

PLASTIC SMALL OUTLINE - NO LEAD



NOTES: (continued)

3. For more information, see QFN/SON PCB application report in literature No. SLUA271 (www.ti.com/lit/slua271).



DRY0006A

EXAMPLE STENCIL DESIGN

USON - 0.6 mm max height

PLASTIC SMALL OUTLINE - NO LEAD



NOTES: (continued)

4. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.



DSF0006A



PACKAGE OUTLINE

X2SON - 0.4 mm max height

PLASTIC SMALL OUTLINE - NO LEAD



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing Per ASME Y14.5M.
 This drawing is subject to change without notice.
 Reference JEDEC registration MO-287, variation X2AAF.



DSF0006A

EXAMPLE BOARD LAYOUT

X2SON - 0.4 mm max height

PLASTIC SMALL OUTLINE - NO LEAD



NOTES: (continued)

4. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slua271).



DSF0006A

EXAMPLE STENCIL DESIGN

X2SON - 0.4 mm max height

PLASTIC SMALL OUTLINE - NO LEAD



4. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.



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